



*ITW*

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Applicant:

Alessia Pavan et al.

Serial No.: 10/749,130

Filed: December 30, 2003

For: Non-Volatile Memory Cell  
Comprising Dielectric Layers  
Having a Low Dielectric  
Constant and Corresponding  
Manufacturing Process

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Art Unit: 2894

Examiner: Amar Movva

Docket: NUM.0104US  
02-AG-317

Mail Stop **Amendment**  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**REPLY TO OFFICE ACTION**

Sir:

In response to the office action mailed August 13, 2008, please amend the above-referenced patent application as follows:

Date of Deposit: October 23, 2008

I hereby certify under 37 CFR 1.8(a) that this correspondence is being deposited with the United States Postal Service as **first class mail** with sufficient postage on the date indicated above and is addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

*Cynthia L. Hayden*  
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